NSN 5962-01-447-5748

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View Online at https://aerobasegroup.com/nsn/5962-01-447-5748

Body Length:
1.060 inches
Body Width:
0.310 inches
Body Height:
0.185 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Electrostatic sensitive and monolithic and burn in and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Input Circuit Pattern:
16 input
Current Rating Per Characteristic:
70.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
Bit ind. Decoder 1
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
20.00 nanoseconds acc/pac detector tint control
Memory Device Type:
Pal
Special Features:
Nuclear hardness critical items
Nuclear Hardness Critical Feature:
Hardened
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 printed circuit
Shelf Life:
N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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